			<u> </u>	Sheet 1 o	f <u>1</u>								
Form PTO-1449 (Rev. 7-83)		U.S. Department of Commerce Patent and Trademark Office				ATTY. DOCKET NO. 5833-A-13				SERIAL NO. 09/766,798			
OIPE	FORMATI	ON DISCLOSURE	CITATION		APPLICAI	NT: JAMIN	I LING E	T AL.					
JUN 2 1 2001	(Use several sheets if necessary)				FILING DATE 01/22/2001				GROUP 2816				
RADEMARK	74		U.S. PA	TENT DOCU	MENTS			<u> </u>					
EXAMINER 'S INITIALS	EXHIBIT NUMBER	DOCUMENT NO.	DATE	N	AME	CL	ASS	SUBG	CLASS	FILING	S DATE		
TW		4,808,769	02/28/89	Nakano et a	al.		Ĵ.		Ì				
TTN		4,857,671	08/1●/95	Nakano et a	al.								
TON		4,970,571	11/13/90	Yamakawa	et al.								
DN		5,212,138	05/18/93	Krulik et al.									
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TIN		6,094,058	07/25/00	Hembree et	al.			<u></u>	<u> </u>				
			FOREIGN P	ATENT DO	UMENTS								
EXAMINER'S INITIALS	EXHIBIT NUMBER	DOCUMENT NUMBER	DATE	COUN	NTRY	CLAS	CLASS S		SUBCLASS		TRANSLATION		
										YES	NO		
NET		-JP411140658A	03/23/9\$	Japa	<u> </u>								
		OTHER	DOCUMENTS	(Including Author	, Titla, Data, Pe	rtinant Pagas,	Etc.)						
	1	Strandjord, A., et Semiconductors,					Nickel	/Gold Pl	ating o	n Copper	Based		

*EXAMINER: Initial if citation—sonstance and not considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant

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TTN		6,097,087	08/01/00	Farnworth et al.							
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		OTHER	DOCUMENT	S (Including Autho	or, Title, Date, Perti	nent Pages, Etc.)	<u>l</u>	<u> </u>			
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	3	Stepniak, F., Solo PACK 1997.	der Flip ChipsE	mploying Ele	ctroless Nick	el: An Evaluat	tion of Reliabilit	y and Cost	, Inter.		
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	6	O'Sullivan, E., et 42, No. 5 - Electi				riers for micro	oelectronics, IB	M J.R.&D.	, Vol.		
	7	HBS Technical Prop dated May 1999	oosal #990505-2	2.OSH, "HBS N	fark II Automa	tic Electroless	Nickel/Immersion	Gold Plate	Γool,"		
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		considered, whether red. Include copy of t					e through citation	if not in ;			